

091698

CD4538B Types

CMOS Dual Precision Monostable Multivibrator

High-Voltage Types (20-Volt Rating)

Features:

- Retriggerable/resettable capability
- Trigger and reset propagation delays independent of R_x , C_x
- Triggering from leading or trailing edge
- Q and \bar{Q} buffered outputs available
- Separate resets
- Wide range of output-pulse widths
- Schmitt trigger input allows unlimited rise and fall times on +TR and -TR inputs

The RCA-CD4538B dual precision monostable multivibrator provides stable retriggerable/resettable one-shot operation for any fixed-voltage timing application.

An external resistor (R_x) and an external capacitor (C_x) control the timing and accuracy for the circuit. Adjustment of R_x and C_x provides a wide range of output pulse widths from the Q and \bar{Q} terminals. The time delay from trigger input to output transition (trigger propagation delay) and the time delay from reset input to output transition (reset propagation delay) are independent of R_x and C_x . Precision control of output pulse widths is achieved through linear CMOS techniques.

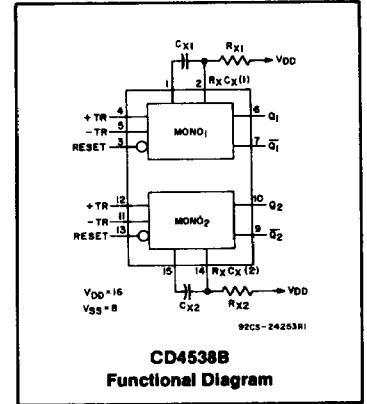
Leading-edge-triggering (+TR) and trailing-edge-triggering (-TR) inputs are provided for triggering from either edge of an input pulse. An unused +TR input should be tied to V_{SS} . An unused -TR input should be tied to V_{DD} . A RESET (on low level) is provided for immediate termination of the output pulse or to prevent output pulses when power is turned on. An unused RESET input should be tied to V_{DD} . However, if an entire section of the CD4538B is not used, its inputs must be tied to either V_{DD} or V_{SS} . See Table I.

In normal operation the circuit retriggers (extends the output pulse one period) on the application of each new trigger pulse. For operation in the non-retriggerable mode, \bar{Q} is connected to -TR when leading-edge triggering (+TR) is used or Q is connected to +TR when trailing-edge triggering (-TR) is used. The time period (T) for this multivibrator can be calculated by: $T=R_x C_x$.

The minimum value of external resistance, R_x , is 4 K Ω . The maximum and minimum values of external capacitance, C_x , are 100 μ F and 5000 pF, respectively.

The CD4538B types are supplied in 16-lead hermetic dual-in-line ceramic packages (D and F suffixes), 16-lead dual-in-line plastic packages (E suffix), 16-lead ceramic flat packages (K suffix), and in chip form (H suffix).

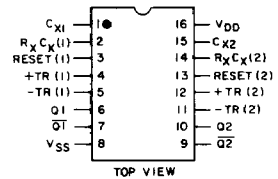
The CD4538B is similar to type MC14538 and is pin-for-pin compatible with the CD4098B.



- 100% tested for maximum quiescent current at 20 V
- Maximum input current of 1 μ A at 18 V over full package-temperature range; 100 nA at 18 V and 25 $^{\circ}$ C
- Noise margin (full package-temperature range):
 - 1 V at $V_{DD}=5$ V
 - 2 V at $V_{DD}=10$ V
 - 2.5 V at $V_{DD}=15$ V
- 5-V, 10-V, and 15-V parametric ratings
- Standardized, symmetrical output characteristics
- Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices."

Applications:

- Pulse delay and timing
- Pulse shaping



TERMINALS 1, 8, 15 ARE ELECTRICALLY CONNECTED INTERNALLY

92CS-24 B48R1

Terminal Assignment

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MAXIMUM RATINGS, Absolute-Maximum Values:

DC SUPPLY-VOLTAGE RANGE, (V_{DD})	-0.5 to +20 V
(Voltages referenced to V_{SS} Terminal)	-0.5 to $V_{DD} + 0.5$ V
INPUT VOLTAGE RANGE, ALL INPUTS	± 10 mA
DC INPUT CURRENT, ANY ONE INPUT	
POWER DISSIPATION PER PACKAGE (P_D):	500 mW
For $T_A = -40$ to $+60^\circ\text{C}$ (PACKAGE TYPE E)	Derate Linearly at 12 mW/ $^\circ\text{C}$ to 200 mW
For $T_A = +60$ to $+85^\circ\text{C}$ (PACKAGE TYPE E)	500 mW
For $T_A = -55$ to $+100^\circ\text{C}$ (PACKAGE TYPES D, F, K)	Derate Linearly at 12 mW/ $^\circ\text{C}$ to 200 mW
For $T_A = +100$ to $+125^\circ\text{C}$ (PACKAGE TYPES D, F, K)	
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	100 mW
OPERATING-TEMPERATURE RANGE (All Package Types)	
FOR $T_A = \text{FULL PACKAGE-TEMPERATURE RANGE}$	-55 to $+125^\circ\text{C}$
OPERATING-TEMPERATURE RANGE (T_A):	-40 to $+85^\circ\text{C}$
PACKAGE TYPES D, F, K, H	-65 to $+150^\circ\text{C}$
PACKAGE TYPE E	
STORAGE TEMPERATURE RANGE (T_{stg})	
LEAD TEMPERATURE (DURING SOLDERING):	$+265^\circ\text{C}$
At distance $1/16 \pm 1/32$ in. (1.59 ± 1.79 mm) from case for 10 s max.	

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, normal operating conditions should be selected so that operating is always within the following ranges:

CHARACTERISTIC	V_{DD} (V)	LIMITS		UNITS
		Min.	Max.	
Supply-Voltage Range (For $T_A = \text{Full Package-Temperature Range}$)	—	3	18	V
Input Pulse Width t_{WH} , t_{WL} +TR, -TR, or RESET	5	140	—	ns
	10	80	—	
	15	60	—	

TABLE I
CD4538B FUNCTIONAL TERMINAL CONNECTIONS

FUNCTION	V_{DD} TO TERM. NO.		V_{SS} TO TERM. NO.		INPUT PULSE TO TERM. NO.		OTHER CONNECTIONS	
	MONO ₁	MONO ₂	MONO ₁	MONO ₂	MONO ₁	MONO ₂	MONO ₁	MONO ₂
Leading-Edge Trigger/ Retriggerable	3, 5	11, 13			4	12		
Leading-Edge Trigger/ Non-Retriggerable	3	13			4	12	5-7	11-9
Trailing-Edge Trigger/ Retriggerable	3	13	4	12	5	11		
Trailing-Edge Trigger/ Non-Retriggerable	3	13			5	11	4-6	12-10

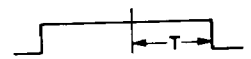
INPUT PULSE TRAIN



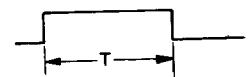
NOTES:

- A RETRIGGERABLE ONE-SHOT MULTIVIBRATOR HAS AN OUTPUT PULSE WIDTH WHICH IS EXTENDED ONE FULL TIME PERIOD (T) AFTER APPLICATION OF THE LAST TRIGGER PULSE.
- A NON-RETRIGGERABLE ONE-SHOT MULTIVIBRATOR HAS A TIME PERIOD (T) REFERENCED FROM THE APPLICATION OF THE FIRST TRIGGER PULSE.

RETRIGGERABLE MODE PULSE WIDTH (+TR MODE)



NON-RETRIGGERABLE MODE PULSE WIDTH (+TR MODE)



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STATIC ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	CONDITIONS			LIMITS AT INDICATED TEMPERATURES (°C)							UNITS
				Values at -55, +25, +125 Apply to D, F, K, H Pkgs. Values at -40, +25, +85 Apply to E Pkgs.							
	V _O (V)	V _{IN} (V)	V _{DD} (V)	-55	-40	+85	+125	Min.	+25 Typ.	Max.	
Quiescent Device Current, I _{DD} Max.	—	0,5	5	5	5	150	150	—	0.04	5	
	—	0,10	10	10	10	300	300	—	0.04	10	
	—	0,15	15	20	20	600	600	—	0.04	20	
	—	0,20	20	100	100	3000	3000	—	0.08	100	
Output Low (Sink) Current, I _{OL} Min.	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	—	
	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6	—	
	1.5	0,15	15	4.2	4	2.8	2.4	3.4	6.8	—	
Output High (Source) Current, I _{OH} Min.	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	—	
	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	—	
	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	—	
	13.5	0,15	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8	—	
Output Voltage: Low-Level, V _{OL} Max.	—	0,5	5	0.05				—	0	0.05	
	—	0,10	10	0.05				—	0	0.05	
	—	0,15	15	0.05				—	0	0.05	
Output Voltage: High-Level, V _{OH} Min.	—	0,5	5	4.95				4.95	5	—	
	—	0,10	10	9.95				9.95	10	—	
	—	0,15	15	14.95				14.95	15	—	
Input Low Voltage, V _{IL} Max.	0.5,4.5	—	5	1.5				—	—	1.5	
	1,9	—	10	3				—	—	3	
	1.5,13.5	—	15	4				—	—	4	
Input High Voltage, V _{IH} Min.	0.5,4.5	—	5	3.5				3.5	—	—	
	1,9	—	10	7				7	—	—	
	1.5,13.5	—	15	11				11	—	—	
Input Current, I _{IN} Max.	—	0,18	18	±0.1	±0.1	±1	±1	—	±10 ⁻⁵	±0.1	

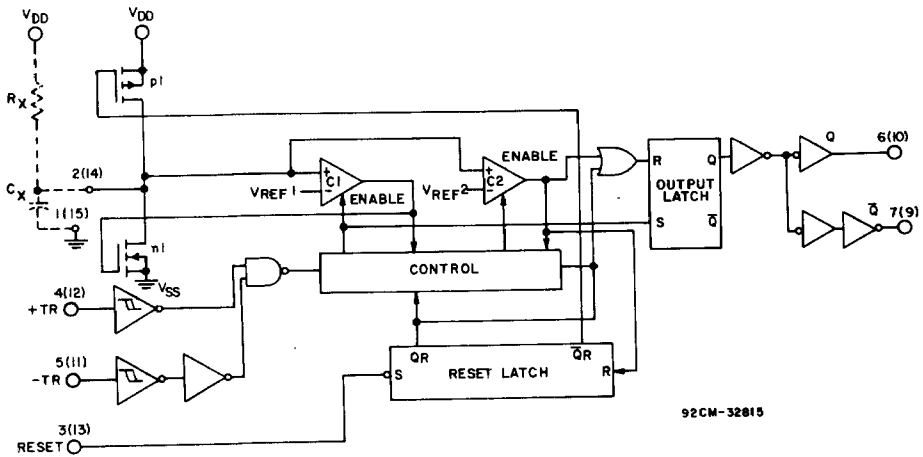


Fig. 1 - Logic diagram (1/2 of device shown).

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DYNAMIC ELECTRICAL CHARACTERISTICS, At $T_A=25^\circ\text{C}$; Input $t_r, t_f=20\text{ ns}$, $C_L=50\text{ pF}$

CHARACTERISTIC	TEST CONDITIONS	LIMITS			UNITS	
		V_{DD} (V)	Min.	Typ.		Max.
Transition Time t_{TLH}, t_{THL}		5	—	100	200	ns
		10	—	50	100	
		15	—	40	80	
Propagation Delay Time: +TR or -TR to Q or \bar{Q}		5	—	300	600	
		10	—	150	300	
		15	—	100	220	
Reset to Q or \bar{Q}		5	—	250	500	
		10	—	125	250	
		15	—	95	190	
Minimum Input Pulse Width: +TR, -TR or Reset		5	—	80	140	
		10	—	40	80	
		15	—	30	60	
Output Pulse Width - Q or \bar{Q} : $C_x=0.005\text{ }\mu\text{F}$, $R_x=10\text{ K}\Omega^*$	T	5	57	60.6	64.5	μs
		10	55	58.9	63.0	
		15	55	59.1	63.5	
$C_x=0.1\text{ }\mu\text{F}$, $R_x=100\text{ K}\Omega$		5	9.4	9.97	10.5	ms
		10	9.4	9.95	10.6	
		15	9.5	10.00	10.6	
$C_x=10\text{ }\mu\text{F}$, $R_x=100\text{ K}\Omega$		5	0.95	1.00	1.06	s
		10	0.95	1.00	1.06	
		15	0.96	1.01	1.07	
Pulse Width Match between circuits in same package: $C_x=0.1\text{ }\mu\text{F}$, $R_x=100\text{ K}\Omega$	$100(T_1-T_2)$ T_1	5	—	± 1	—	%
		10	—	± 1	—	
		15	—	± 1	—	
Minimum Retrigger Time	t_r	5	0	—	—	ns
		10	0	—	—	
		15	0	—	—	
Input Capacitance	C_{IN}	Any Input	—	5.0	7.5	pF

*Note: Minimum R_x value=4 K Ω , minimum C_x value=5000 pF.

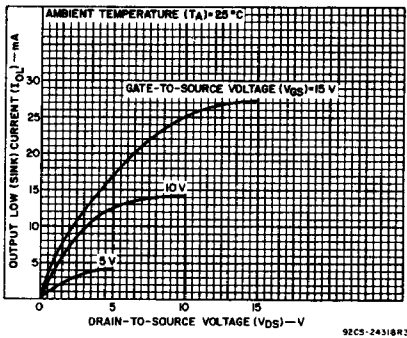


Fig. 2 - Typical output low (sink) current characteristics.

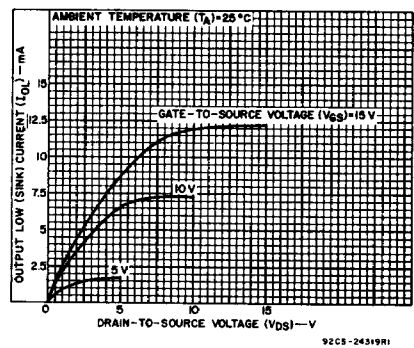


Fig. 3 - Minimum output low (sink) current characteristics.

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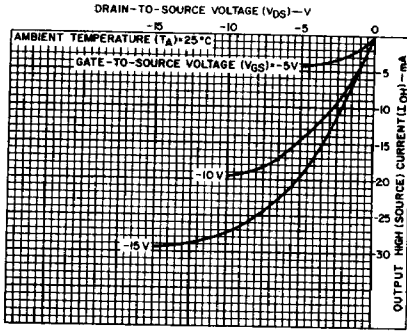


Fig. 4 - Typical output high (source) current characteristics.

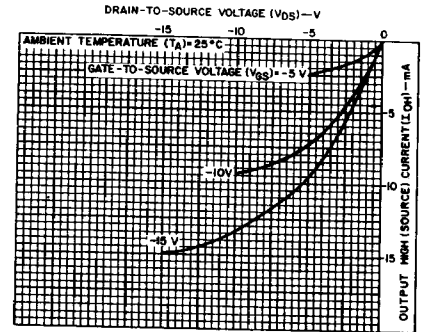


Fig. 5 - Minimum output high (source) current characteristics.

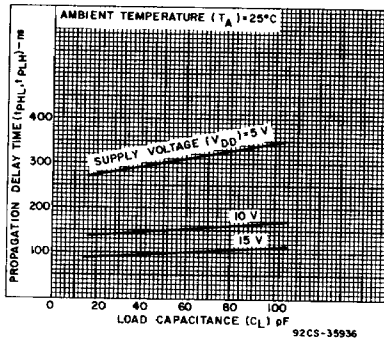


Fig. 6 - Typical propagation delay time as a function of load capacitance (+TR or -TR to Q or \bar{Q}).

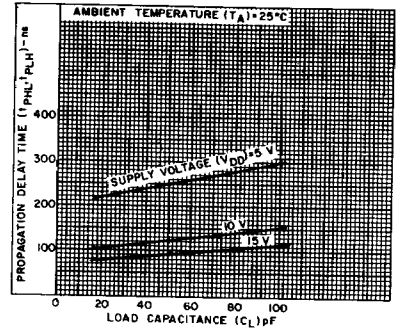


Fig. 7 - Typical propagation delay time as a function of load capacitance (RESET to Q or \bar{Q}).

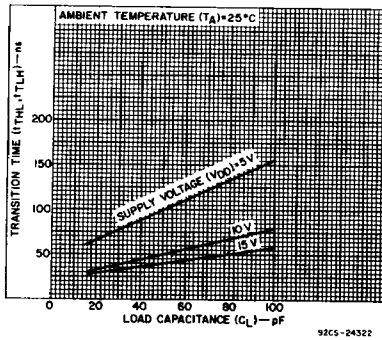


Fig. 8 - Typical transition time as a function of load capacitance.

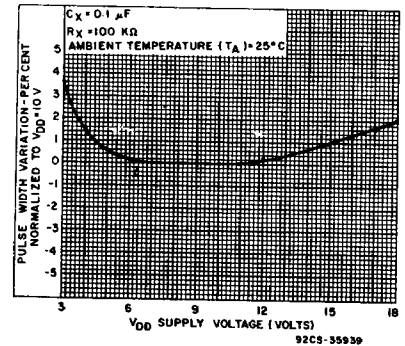


Fig. 9 - Typical pulse-width variation as a function of supply voltage.

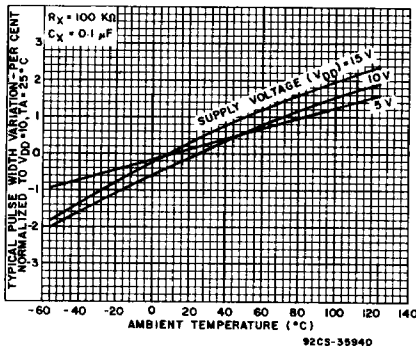


Fig. 10 - Typical pulse-width variation as a function of temperature ($R_X=100\text{ K}\Omega$, $C_X=0.1\text{ }\mu\text{F}$).

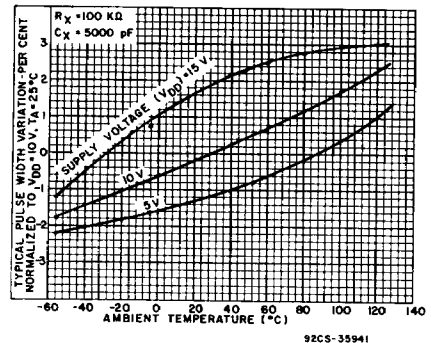


Fig. 11 - Typical pulse-width variation as a function of temperature ($R_X=100\text{ K}\Omega$, $C_X=5000\text{ pF}$).

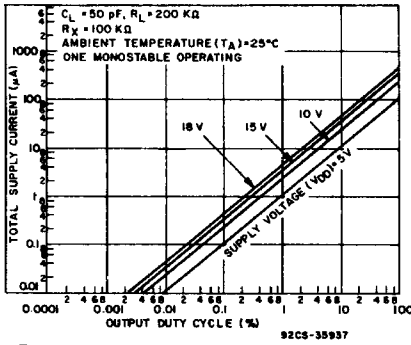


Fig. 12 - Typical total supply current as a function of output duty cycle.

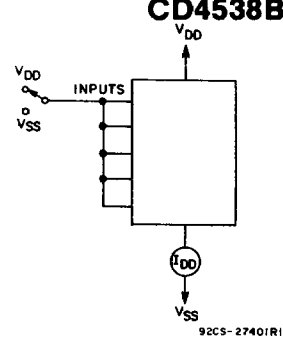
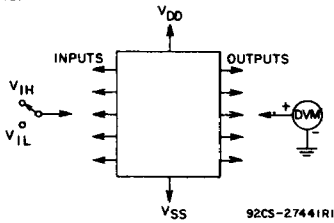


Fig. 13 - Quiescent device current test circuit.



Test any combination of inputs.

Fig. 14 - Input-voltage test circuit.

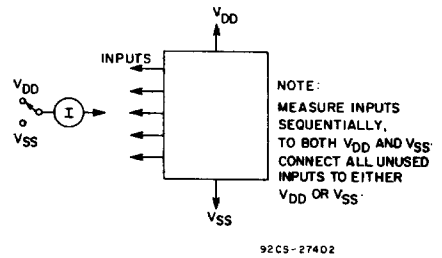


Fig. 15 - Input-leakage current test circuit.

Power-Down Mode

During a rapid power-down condition, as would occur with a power-supply short circuit or with a poorly filtered power supply, the energy stored in C_X could discharge into Pin 2 or 14. To avoid possible device damage in this mode, when C_X is ≥ 0.5 microfarad, a protection diode with a 1-ampere or higher rating (1N5395 or equivalent) and a separate ground return for C_X should be provided as shown in Fig. 16.

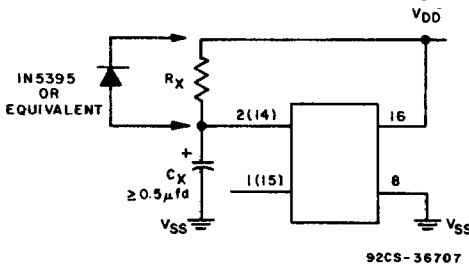


Fig. 16 - Rapid power-down protection circuit.

An alternate protection method is shown in Fig. 17, where a 51-ohm current-limiting resistor is inserted in series with C_X . Note that a small pulse width decrease will occur however, and R_X must be appropriately increased to obtain the originally desired pulse width.

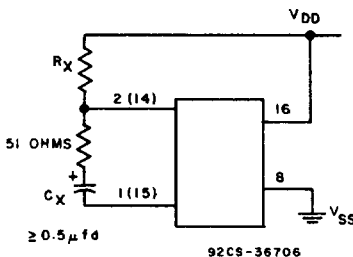
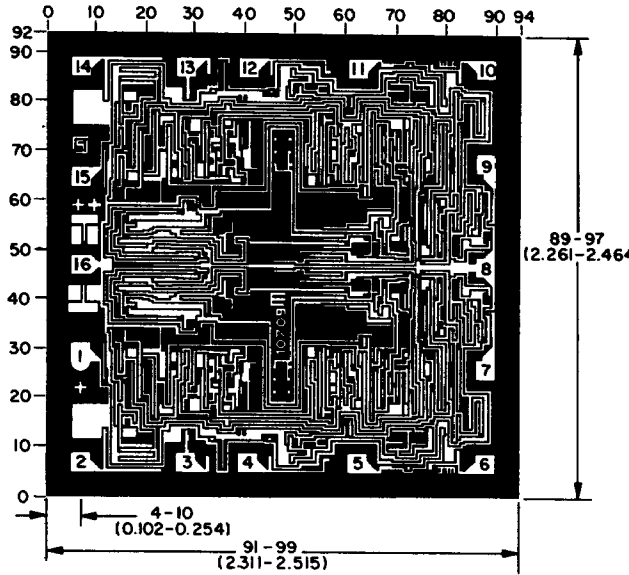


Fig. 17 - Alternate rapid power-down protection circuit.



Dimensions and pad layout for CD4538BH.

Dimensions in parentheses are in millimeters and are derived from the basic inch dimension as indicated. Grid graduations are in mils (10^{-3} inch).

The photographs and dimensions of each CMOS chip represent a chip when it is part of the wafer. When the wafer is separated into individual chips, the angle of cleavage may vary with respect to the chip face for different chips. The actual dimensions of the isolated chip, therefore, may differ slightly from the nominal dimensions shown. The user should consider a tolerance of -3 mils to $+16$ mils applicable to the nominal dimensions shown.